

SCDS142A-OCTOBER 2003-REVISED MARCH 2005

FEATURES

- High-Bandwidth Data Path (Up To 500 MHz (1))
- 5-V Tolerant I/Os With Device Powered Up or Powered Down
- Low and Flat ON-State Resistance (r_{on}) Characteristics Over Operating Range (r_{on} = 4.5 Ω Typ)
- Rail-to-Rail Switching on Data I/O Ports

 0- to 5-V Switching With 3.3-V V_{CC}
 - 0- to 3.3-V Switching With 2.5-V $\rm V_{\rm CC}$
- B-Port Outputs Are Precharged by Bias
 Voltage (BIASV) to Minimize Signal Distortion
 During Live Insertion and Hot Plugging
- Supports PCI Hot Plug
- Bidirectional Data Flow With Near-Zero Propagation Delay
- Low Input/Output Capacitance Minimizes Loading and Signal Distortion (C_{io(OFF)} = 3.5 pF Typ)
- (1) For additional information regarding the performance characteristics of the CB3Q family, refer to the TI application report, *CBT-C, CB3T, and CB3Q Signal-Switch Families*, literature number SCDA008.

- Fast Switching Frequency (f_{ON}= 20 MHz Max)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption (I_{cc} = 0.75 mA Typ)
- V_{cc} Operating Range From 2.3 V to 3.6 V
- Data I/Os Support 0- to 5-V Signaling Levels (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Supports Both Digital and Analog Applications: PCI Interface, Differential Signal Interface, Memory Interleaving, Bus Isolation, Low-Distortion Signal Gating

DBQ, DGV, OR PW PACKAGE (TOP VIEW)

ON	d	1	σ	24	Ь	V _{CC}			
A1	D	2		23	þ	B1			
A2	[3		22	þ	B2			
A3	[4		21	þ	B3			
A4	П	5		20	þ	B4			
A5	[6		19	þ	B5			
A6	Π	7		18	þ	B6			
A7	[8		17	þ	B7			
A8	D	9		16	þ	B8			
A9	[10		15		B9			
A10	D	11		14	þ	B10			
GND	C	12		13	þ	BIAS∖			



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TEXAS INSTRUMENTS www.ti.com

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DESCRIPTION/ORDERING INFORMATION

The SN74CB3Q6800 is a high-bandwidth FET bus switch utilizing a charge pump to elevate the gate voltage of the pass transistor, providing a low and flat ON-state resistance (r_{on}). The low and flat ON-state resistance allows for minimal propagation delay and supports rail-to-rail switching on the data input/output (I/O) ports. The device also features low data I/O capacitance to minimize capacitive loading and signal distortion on the data bus. Specifically designed to support high-bandwidth applications, the SN74CB3Q6800 provides an optimized interface solution ideally suited for broadband communications, networking, and data-intensive computing systems.

The SN74CB3Q6800 is a 10-bit bus switch with a single output-enable (\overline{ON}) input. When \overline{ON} is low, the 10-bit bus switch is ON and the A port is connected to the B port, allowing bidirectional data flow between ports. When \overline{ON} is high, the 10-bit bus switch is OFF and a high-impedance state exists between the A and B ports. The B port is precharged to bias voltage (BIASV) through the equivalent of a 10-k Ω resistor when \overline{ON} is high, or if the device is powered down (V_{CC} = 0 V).

During insertion (or removal) of a card into (or from) an active bus, the card's output voltage may be close to GND. When the connector pins make contact, the card's parasitic capacitance tries to force the bus signal to GND, creating a possible glitch on the active bus. This glitching effect can be reduced by using a bus switch with precharged bias voltage (BIASV) of the bus switch equal to the input threshold voltage level of the receivers on the active bus. This method ensures that any glitch produced by insertion (or removal) of the card does not cross the input threshold region of the receivers on the active bus, minimizing the effects of live-insertion noise.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry prevents damaging current backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, \overline{ON} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
1000 10 0500	SSOP (QSOP) – DBQ	Tape and reel	SN74CB3Q6800DBQR	CB3Q6800
	TSSOP – PW	Tube	SN74CB3Q6800PW	DV000
–40°C to 85°C	1350P - PW	Tape and reel	SN74CB3Q6800PWR	- BY800
	TVSOP – DGV	Tape and reel	SN74CB3Q6800DGVR	BY800

ORDERING INFORMATION

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

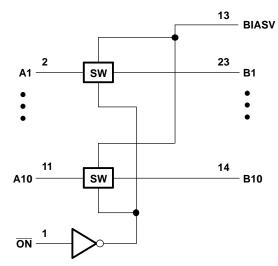
	INPUT/OUTPUT A	FUNCTION
L	В	A port = B port
н	Z	Disconnect B port = BIASV

TEXAS INSTRUMENTS www.ti.com

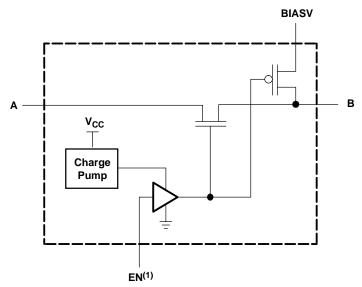
SN74CB3Q6800 10-BIT FET BUS SWITCH WITH PRECHARGED OUTPUTS 2.5-V/3.3-V LOW-VOLTAGE HIGH-BANDWIDTH BUS SWITCH

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LOGIC DIAGRAM (POSITIVE LOGIC)



SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



 $^{(1)}\,$ EN is the internal enable signal applied to the switch.

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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	4.6	V
BIASV	BIAS supply voltage range		-0.5	7	V
V _{IN}	Control input voltage range ⁽²⁾⁽³⁾	-0.5	7	V	
V _{I/O}	Switch I/O voltage range ⁽²⁾⁽³⁾⁽⁴⁾		-0.5	7	V
I _{IK}	Control input clamp current	V _{IN} < 0		-50	mA
I _{I/OK}	I/O port clamp current	V _{I/O} < 0		-50	mA
I _{I/O}	ON-state switch current ⁽⁵⁾			±64	mA
	Continuous current through V _{CC} or GND			±100	mA
		DBG package		61	
θ_{JA}	Package thermal impedance ⁽⁶⁾	DGV package PW package		86	°C/W
l				88	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to ground, unless otherwise specified.

(3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(4) V_{l} and V_{O} are used to denote specific conditions for $V_{l/O}$.

(5) I_I and I_O are used to denote specific conditions for $I_{I/O}$.

(6) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage				V
BIASV	Bias supply voltage		0	5	V
V	High level control input voltage $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.7	5.5	V
VIH	High-level control input voltage	V_{CC} = 2.7 V to 3.6 V	2	5.5	
V		V_{CC} = 2.3 V to 2.7 V	0 0.7		V
VIL	Low-level control input voltage	V_{CC} = 2.7 V to 3.6 V	0	0.8	v
V _{I/O}	Data input/output voltage		0	5.5	V
T _A	Operating free-air temperature		-40	85	°C

 All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004. BIASV is a supply voltage, not a control input.

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Electrical Characteristics⁽¹⁾

over recommended operating free-air temperature range (unless otherwise noted)

P	ARAMETER			(P(2)	МАХ	UNIT		
V _{IK}		V _{CC} = 3.6 V,	I _I = -18 mA				-1.8	V
I _{IN}	Control inputs	V _{CC} = 3.6 V,	V _{IN} = 0 to 5.5 V				±1	μΑ
I _O	B port	$V_{CC} = 3.V,$	BIASV = 2.4 V, V _O = 0,	Switch OFF, V _{IN} = V _{CC} or GND		0.2		mA
I _{OZ} ⁽³⁾		V _{CC} = 3.6 V,	$V_{O} = 0$ to 5.5 V, $V_{I} = 0$,	Switch OFF, $V_{IN} = V_{CC}$ or GND			±1	μA
I _{off}		$V_{CC} = 0,$	$V_0 = 0$ to 5.5 V,	V ₁ = 0			1	μΑ
I _{CC}		V _{CC} = 3.6 V,	l _{I/O} = 0, Switch ON or OFF,	$V_{IN} = V_{CC}$ or GND	0	.75	2	mA
$\Delta I_{CC}^{(4)}$	Control inputs	V _{CC} = 3.6 V,	One input at 3 V,	Other inputs at V_{CC} or GND			30	μA
I (5)	Den eentrel innut	V _{CC} = 3.6 V,	A and B ports open,		0	20	0.45	mA/
$I_{CCD}^{(5)}$	Per control input	Control input switching a	at 50% duty cycle	0	.38	0.45	MHz	
C _{in}	Control inputs	V _{CC} = 3.3 V,	V _{IN} = 5.5 V, 3.3 V, or 0			2.5	3.5	pF
C _{io(OF} F)	A port	V _{CC} = 3.3 V,	Switch OFF, V _{IN} = V _{CC} or GND,	$V_{I/O} = 5.5 V, 3.3 V, or 0$		3.5	5	pF
C _{io(ON)}		V _{CC} = 3.3 V,	Switch ON, V _{IN} = V _{CC} or GND,	$V_{I/O}$ = 5.5 V, 3.3 V, or 0		9	11	pF
		V _{CC} = 2.3 V,	$V_1 = 0,$	I _O = 30 mA		4.5	8	
r (6)		TYP at V _{CC} = 2.5 V	$V_1 = 1.7 V,$	I _O = -15 mA		4.8	9	Ω
r _{on} ⁽⁶⁾		V - 2 V	$V_1 = 0,$	I _O = 30 mA		4.5	6	52
		$V_{CC} = 3 V$	V _I = 2.4 V,	I _O = -15 mA		4.6	8	

(1)

 V_{IN} and I_{IN} refer to control inputs. $V_{I},\,V_{O},\,I_{I}$, and I_{O} refer to data pins. All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_{A} = 25°C. (2)

(3) For I/O ports, the parameter I_{OZ} includes the input leakage current.

This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND. (4)

This parameter specifies the dynamic power-supply current associated with the operating frequency of a single control input (5)

(see Figure 2).

Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is (6) determined by the lower of the voltages of the two (A or B) terminals.

Switching Characteristics

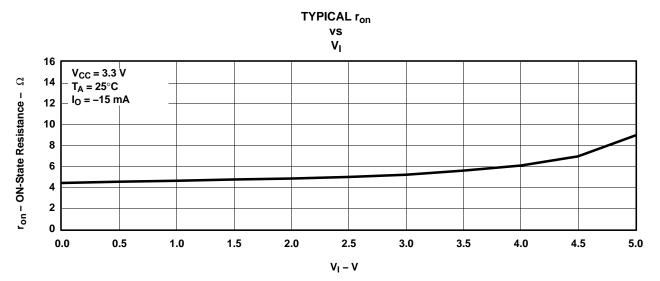
over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	TEST CONDITIONS	FROM	TO (OUTPUT)	V_{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
		(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	
f _{ON} ⁽¹⁾		ON	A or B		10		20	MHz
t _{pd} ⁽²⁾		A or B	B or A		0.135		0.225	ns
t _{PZH}	BIASV = GND	ON	A or B	1.5	8.5	1.5	6.7	20
t _{PZL}	BIASV = 3 V	ON	AUB	1.5	8.5	1.5	6.7	ns
t _{PHZ}	BIASV = GND	ŌN	A or B	1	5	1	5	20
t _{PLZ}	BIASV = 3 V		AUB	1	6.9	1	6.9	ns

(1)

Maximum switching frequency for control input ($V_O > V_{CC}$, $V_I = 5 V$, $R_L \ge 1 M\Omega$, $C_L = 0$). The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load (2)capacitance, when driven by an ideal voltage source (zero output impedance).

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Figure 1. Typical ron vs VI

TYPICAL ICC vs **ON SWITCHING FREQUENCY**

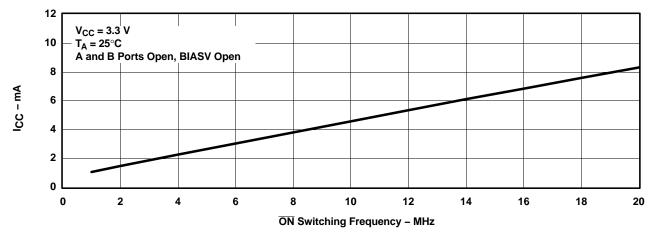
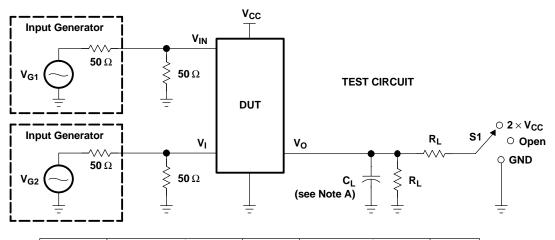


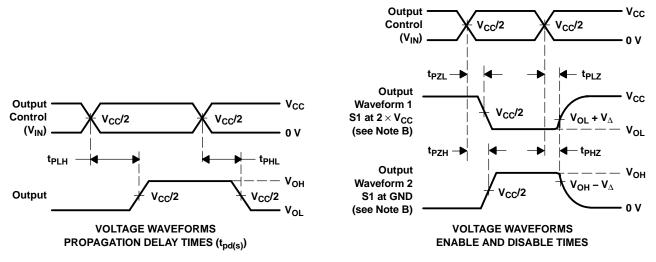
Figure 2. Typical I_{CC} vs ON Switching Frequency

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PARAMETER MEASUREMENT INFORMATION



TEST	V _{CC}	S1	RL	VI	CL	V_{Δ}
t _{pd(s)}	$\textbf{2.5 V} \pm \textbf{0.2 V}$	Open	500 Ω	V _{CC} or GND	30 pF	
pu(0)	3.3 V \pm 0.3 V	Open	500 Ω	V _{CC} or GND	50 pF	
t _{PLZ} /t _{PZL}	$\textbf{2.5 V} \pm \textbf{0.2 V}$	2 × V _{CC}	500 Ω	GND	30 pF	0.15 V
PLZ/PZL	3.3 V \pm 0.3 V	$2 \times V_{CC}$	500 Ω	GND	50 pF	0.3 V
+/+	$\textbf{2.5 V} \pm \textbf{0.2 V}$	GND	500 Ω	V _{CC}	30 pF	0.15 V
t _{PHZ} /t _{PZH}	3.3 V \pm 0.3 V	GND	500 Ω	V _{CC}	50 pF	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z₀ = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd(s)}. The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Test Circuit and Voltage Waveforms

24-May-2007

PACKAGING INFORMATION

MENTS

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Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74CB3Q6800DBQRE4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
74CB3Q6800DBQRG4	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
74CB3Q6800DGVRE4	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74CB3Q6800DGVRG4	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q6800DBQR	ACTIVE	SSOP/ QSOP	DBQ	24	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN74CB3Q6800DGVR	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q6800PW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q6800PWE4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q6800PWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q6800PWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q6800PWRE4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q6800PWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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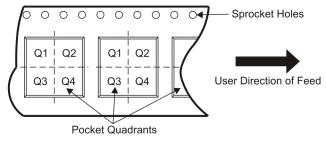
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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

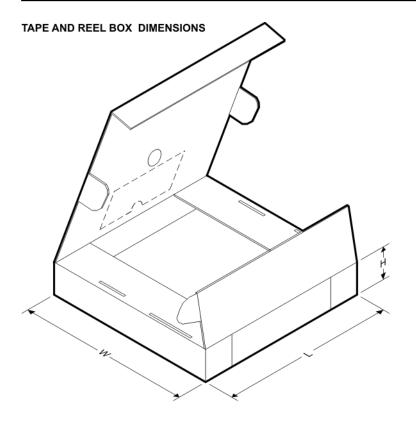


*All dimensions are nominal												
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CB3Q6800DBQR	SSOP/ QSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74CB3Q6800DGVR	TVSOP	DGV	24	2000	330.0	12.4	7.0	5.6	1.6	8.0	12.0	Q1
SN74CB3Q6800PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1



PACKAGE MATERIALS INFORMATION

11-Mar-2008

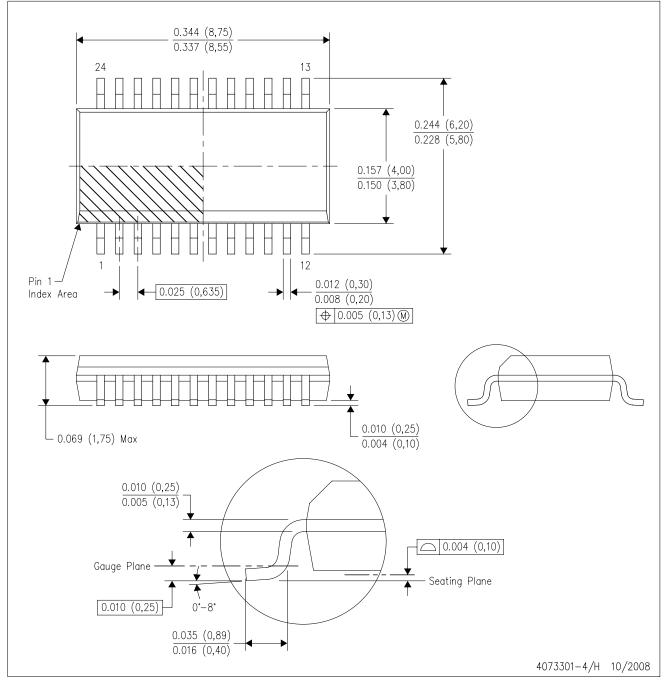


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CB3Q6800DBQR	SSOP/QSOP	DBQ	24	2500	346.0	346.0	33.0
SN74CB3Q6800DGVR	TVSOP	DGV	24	2000	346.0	346.0	29.0
SN74CB3Q6800PWR	TSSOP	PW	24	2000	346.0	346.0	33.0

DBQ (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.

D. Falls within JEDEC MO-137 variation AE.



MECHANICAL DATA

MTSS001C - JANUARY 1995 - REVISED FEBRUARY 1999

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



MECHANICAL DATA

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

DGV (R-PDSO-G**)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



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